

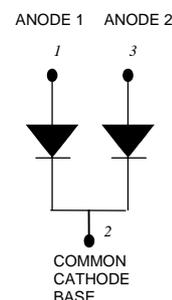
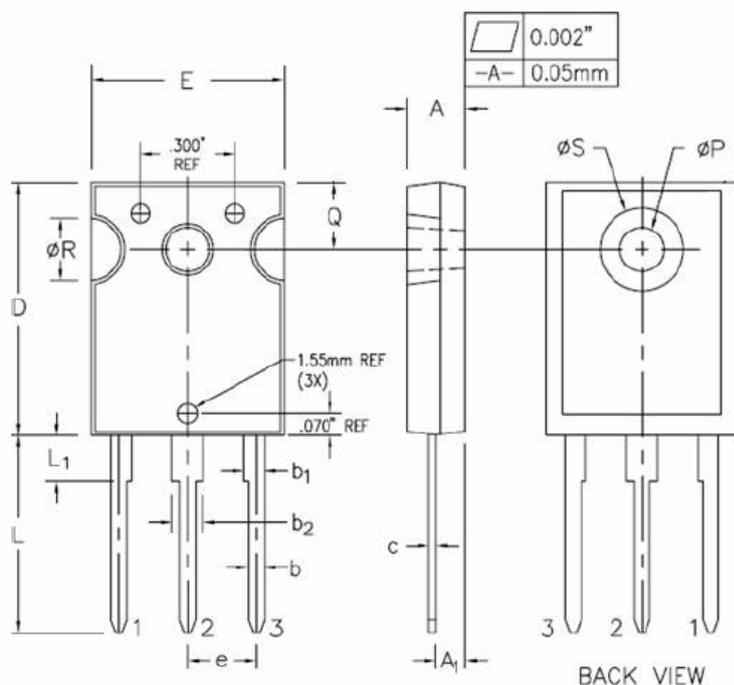
MBR30150WT SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

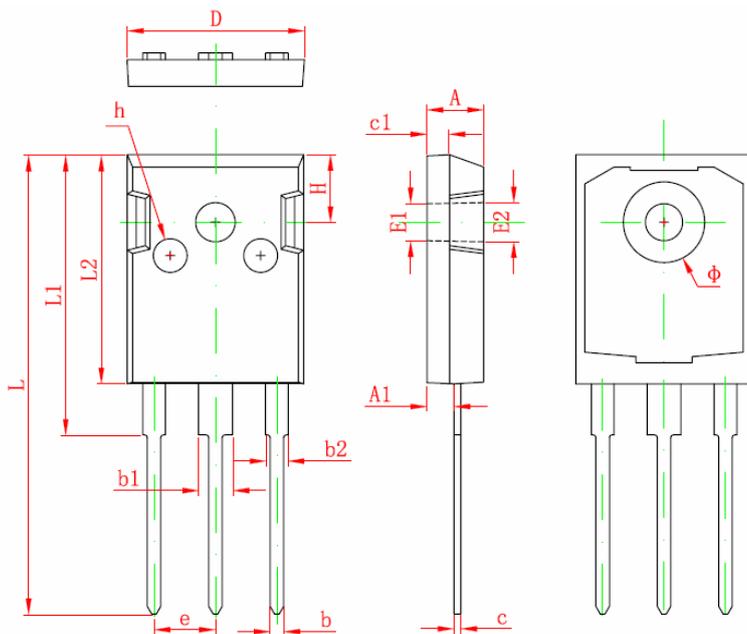
Features:

- 150°C T_J operation
- Center tap TO-247AD package
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request


Mechanical Dimensions: In mm


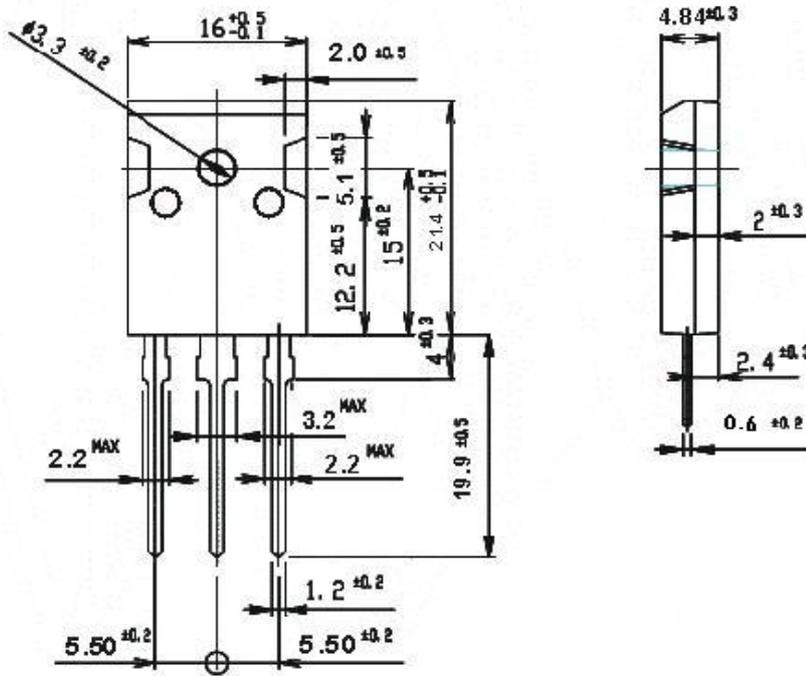
SYMBOL	MILLIMETERS	
	MIN.	MAX.
A	4.58	4.82
A ₁	2.29	2.66
b	1.17	1.35
b ₁	1.53	1.77
b ₂	2.42	2.66
c	0.51	0.71
D	20.32	20.82
E	15.37	15.87
e	5.56	BSC.
L	15.75	16.25
L ₁	3.69	3.93
øP	3.51	3.65
Q	5.34	5.58
øR	4.96	5.20
øS	6.61	6.85

OPTION 1(MX)



Symbol	Dimensions In Millimeters	
	Min	Max
A	4.850	5.150
A1	2.200	2.600
b	1.000	1.400
b1	2.800	3.200
b2	1.800	2.200
c	0.500	0.700
c1	1.900	2.100
D	15.450	15.750
E1	3.500 REF	
E2	3.600 REF	
L	40.900	41.300
L1	24.800	25.100
L2	20.300	20.600
Φ	7.100	7.300
e	5.450 TYP	
H	5.980 REF	
h	0.000	0.300

OPTION 2(CJ)



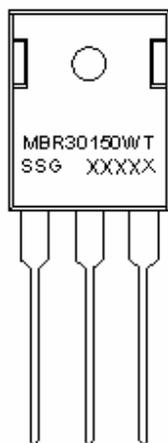
OPTION 3(SR)

TO-247AD

Technical Data
Data Sheet N0768, Rev. -

Green Products

Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type
30 = Forward Current (30A)
150 = Reverse Voltage (150V)
WT = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBR30150WT	TO-247AD (Pb-Free)	30pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	150	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @ $T_C = 105^\circ\text{C}$, rectangular wave form	30	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	408	A

Electrical Characteristics:

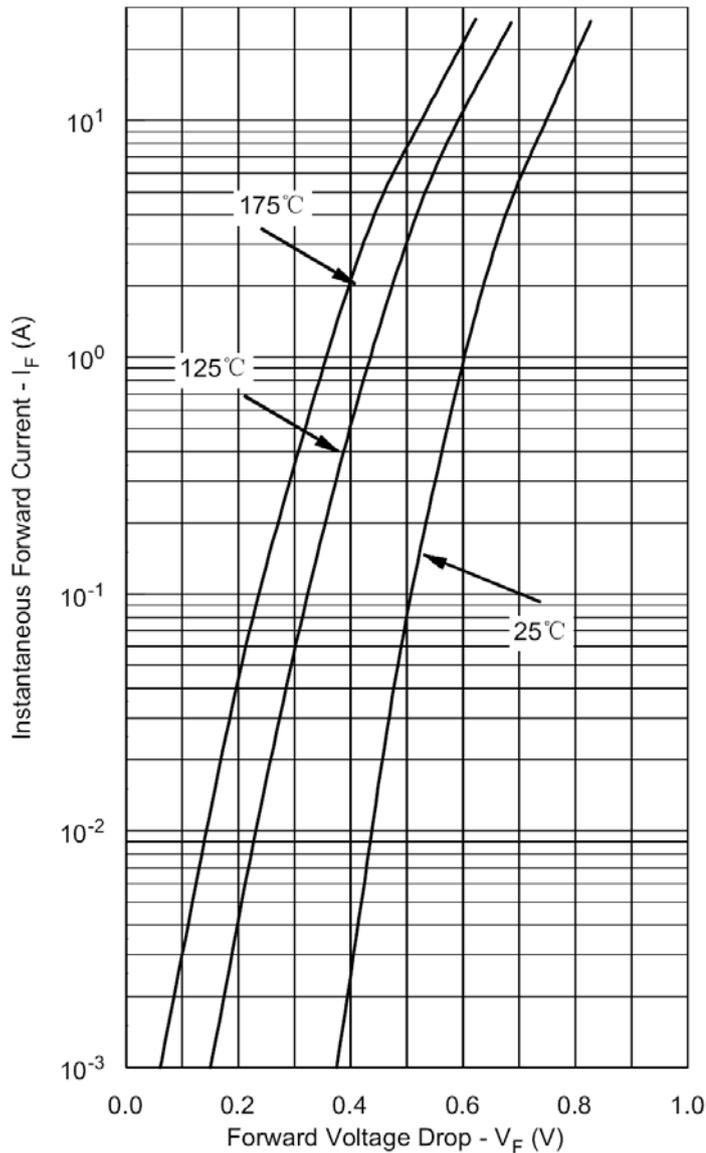
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 15A, Pulse, $T_J = 25\text{ }^\circ\text{C}$	1.00	V
	V_{F2}	@ 15A, Pulse, $T_J = 125\text{ }^\circ\text{C}$	0.78	V
Max. Reverse Current (per leg) *	I_{R1}	@ $V_R = \text{rated } V_R$ $T_J = 25\text{ }^\circ\text{C}$	0.1	mA
	I_{R2}	@ $V_R = \text{rated } V_R$ $T_J = 125\text{ }^\circ\text{C}$	15.0	mA
Max. Junction Capacitance (per leg)	C_T	@ $V_R = 5\text{V}$, $T_C = 25\text{ }^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$	340	pF

* Pulse Width < 300 μ s, Duty Cycle <2%

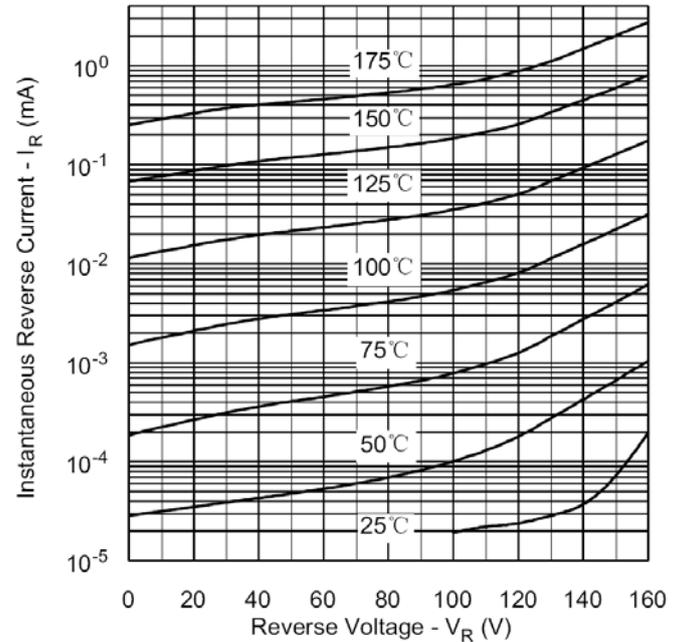
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +150	$^\circ\text{C}$
Max. Storage Temperature	T_{stg}	-	-55 to +150	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	2.20(per leg)	$^\circ\text{C/W}$
			1.10(per device)	
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.24	$^\circ\text{C/W}$
Approximate Weight	wt	-	6.7	g
Case Style	TO-247AD			

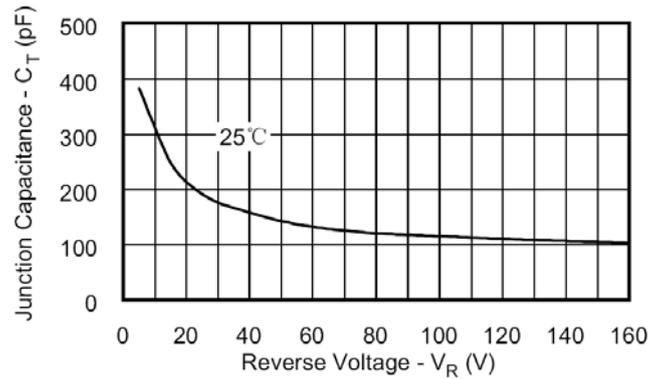
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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